NSN 5961-01-096-3191

Diode Semiconductor Device - Page 1 of 1



View Online at https://e-each-seasons.com/poor/2004-04-000-0404

View Online at https://aerobasegroup.com/nsn/5961-01-096-3191
Inclosure Material:
Glass
Overall Length:
Between 0.120 inches and 0.200 inches
Terminal Length:
Between 1.000 inches and 1.500 inches
Overall Diameter:
Between 0.055 inches and 0.090 inches
End Application:
Test set, ttu-205; radar, series an/sps-4 (v); fire pumps; countermeasure set, an/slq-32; sonar, an/bsy-1(v); test consoles, mini-sac
support equipment, b-52 aircraft, aircraft, sof (ac-130h, mc-130h, ec-130e, hc-130); shipboard material handling equipment (mhe);
support equipment, b-1 aircraft.
Mounting Method:
Terminal
Features Provided:
Hermetically sealed case
Criticality Code Justification:
Feat
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
6.8 regulator voltage
Voltage Tolerance In Percent:
-5.0/+5.0
Current Rating Per Characteristic:
60.00 milliamperes dc current in reverse breakdown region
Power Rating Per Characteristic:
500.0 milliwatts total power dissipation
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius ambient air
Special Features:
Weapon system essential.
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a

No

Unit Of Measure:

Demilitarization: